

## Phase Control Thyristors

$$V_{RRM} = 800-1200 \text{ V}$$

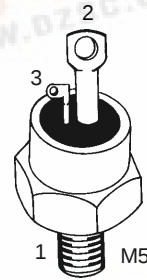
$$I_{T(RMS)} = 25 \text{ A}$$

$$I_{T(AV)M} = 16 \text{ A}$$

| $V_{RSM}$<br>$V_{DSM}$<br>V | $V_{RRM}$<br>$V_{DRM}$<br>V | Type       |
|-----------------------------|-----------------------------|------------|
| 900                         | 800                         | CS 8-08io2 |
| 1300                        | 1200                        | CS 8-12io2 |



TO-64



1 = Anode, 2 = Cathode, 3 = Gate

| Symbol                       | Test Conditions                                                                                                                                   | Maximum Ratings                                                                                                  |
|------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------|
| $I_{T(RMS)}$<br>$I_{T(AV)M}$ | $T_{VJ} = T_{VJM}$<br>$T_{case} = 85^{\circ}\text{C}$ ; 180° sine                                                                                 | 25 A<br>16 A                                                                                                     |
| $I_{TSM}$                    | $T_{VJ} = 45^{\circ}\text{C}$ ;<br>$V_R = 0$                                                                                                      | t = 10 ms (50 Hz), sine 250 A<br>t = 8.3 ms (60 Hz), sine 270 A                                                  |
|                              | $T_{VJ} = T_{VJM}$<br>$V_R = 0$                                                                                                                   | t = 10 ms (50 Hz), sine 200 A<br>t = 8.3 ms (60 Hz), sine 220 A                                                  |
| $I^2t$                       | $T_{VJ} = 45^{\circ}\text{C}$<br>$V_R = 0$                                                                                                        | t = 10 ms (50 Hz), sine 310 A <sup>2</sup> s<br>t = 8.3 ms (60 Hz), sine 306 A <sup>2</sup> s                    |
|                              | $T_{VJ} = T_{VJM}$<br>$V_R = 0$                                                                                                                   | t = 10 ms (50 Hz), sine 200 A <sup>2</sup> s<br>t = 8.3 ms (60 Hz), sine 200 A <sup>2</sup> s                    |
| $(di/dt)_{cr}$               | $T_{VJ} = T_{VJM}$<br>f = 50 Hz, $t_p = 200 \mu\text{s}$<br>$V_D = 2/3 V_{DRM}$<br>$I_G = 0.2 \text{ A}$<br>$di_G/dt = 0.2 \text{ A}/\mu\text{s}$ | repetitive, $I_T = 48 \text{ A}$ 150 A/ $\mu\text{s}$<br>non repetitive, $I_T = I_{T(AV)M}$ 500 A/ $\mu\text{s}$ |
| $(dv/dt)_{cr}$               | $T_{VJ} = T_{VJM}$ ;<br>$R_{GK} = \infty$ ; method 1 (linear voltage rise)                                                                        | $V_{DR} = 2/3 V_{DRM}$ 1000 V/ $\mu\text{s}$                                                                     |
| $P_{GM}$                     | $T_{VJ} = T_{VJM}$<br>$I_T = I_{T(AV)M}$                                                                                                          | $t_p = 30 \mu\text{s}$ 10 W<br>$t_p = 300 \mu\text{s}$ 5 W                                                       |
| $P_{G(AV)}$                  |                                                                                                                                                   | 0.5 W                                                                                                            |
| $V_{RGM}$                    |                                                                                                                                                   | 10 V                                                                                                             |
| $T_{VJ}$                     |                                                                                                                                                   | -40...+125 °C                                                                                                    |
| $T_{VJM}$                    |                                                                                                                                                   | 125 °C                                                                                                           |
| $T_{stg}$                    |                                                                                                                                                   | -40...+125 °C                                                                                                    |
| $M_d$                        | Mounting torque                                                                                                                                   | 2.5 Nm<br>22 lb.in.                                                                                              |
| Weight                       |                                                                                                                                                   | 6 g                                                                                                              |

## Features

- Thyristor for line frequencies
- International standard package JEDEC TO-64
- Planar glassivated chip
- Long-term stability of blocking currents and voltages

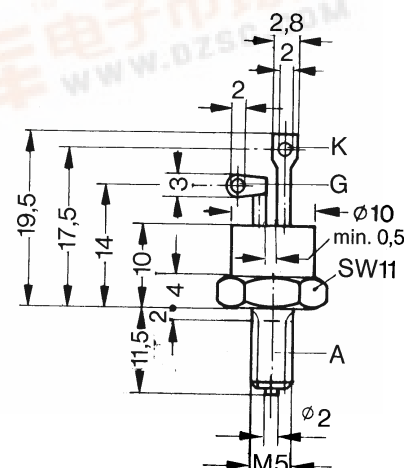
## Applications

- Motor control
- Power converter
- AC power controller

## Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling

## Dimensions in mm (1 mm = 0.0394")



| Symbol     | Test Conditions                                                                                                             | Characteristic Values |
|------------|-----------------------------------------------------------------------------------------------------------------------------|-----------------------|
| $I_R, I_D$ | $T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$                                                                            | $\leq 3$ mA           |
| $V_T$      | $I_T = 33$ A; $T_{VJ} = 25^\circ\text{C}$                                                                                   | $\leq 1.6$ V          |
| $V_{T0}$   | For power-loss calculations only ( $T_{VJ} = 125^\circ\text{C}$ )                                                           | 1.0 V                 |
| $r_T$      |                                                                                                                             | 18 mΩ                 |
| $V_{GT}$   | $V_D = 6$ V; $T_{VJ} = 25^\circ\text{C}$                                                                                    | $\leq 2.5$ V          |
|            | $T_{VJ} = -40^\circ\text{C}$                                                                                                | $\leq 3.5$ V          |
| $I_{GT}$   | $V_D = 6$ V; $T_{VJ} = 25^\circ\text{C}$                                                                                    | $\leq 30$ mA          |
|            | $T_{VJ} = -40^\circ\text{C}$                                                                                                | $\leq 50$ mA          |
| $V_{GD}$   | $T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$                                                                                       | $\leq 0.2$ V          |
| $I_{GD}$   |                                                                                                                             | $\leq 1$ mA           |
| $I_L$      | $T_{VJ} = 25^\circ\text{C}; t_p = 10$ μs<br>$I_G = 0.09$ A; $di_G/dt = 0.09$ A/μs                                           | $\leq 100$ mA         |
| $I_H$      | $T_{VJ} = 25^\circ\text{C}; V_D = 6$ V; $R_{GK} = \infty$                                                                   | $\leq 80$ mA          |
| $t_{gd}$   | $T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$<br>$I_G = 0.09$ A; $di_G/dt = 0.09$ A/μs                                     | $\leq 2$ μs           |
| $t_q$      | $T_{VJ} = T_{VJM}; I_T = 16$ A, $t_p = 300$ μs; $di/dt = -20$ A/μs<br>$V_R = 100$ V; $dv/dt = 20$ V/μs; $V_D = 2/3 V_{DRM}$ | typ. 60 μs            |
| $R_{thJC}$ | DC current                                                                                                                  | 1.5 K/W               |
| $R_{thJH}$ | DC current                                                                                                                  | 2.5 K/W               |
| $d_s$      | Creepage distance on surface                                                                                                | 1.55 mm               |
| $d_A$      | Strike distance through air                                                                                                 | 1.55 mm               |
| $a$        | Max. acceleration, 50 Hz                                                                                                    | 50 m/s <sup>2</sup>   |

Accessories:

Nut M5 DIN 439/SW8

Lock washer A5 DIN 128

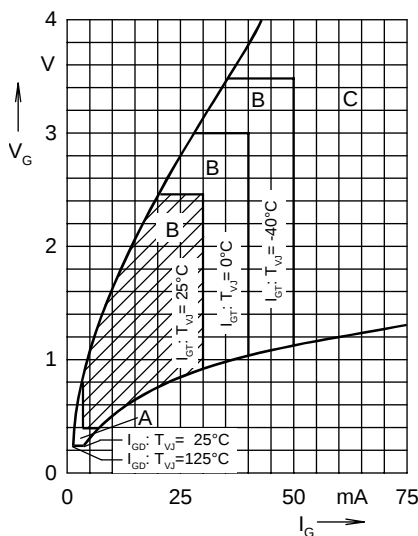


Fig. 1 Gate voltage and gate current Triggering:  
A = no; B = possible; C = safe

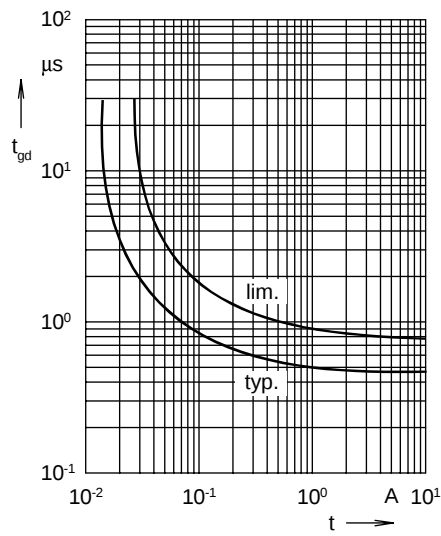


Fig. 2 Gate controlled delay time  $t_{gd}$

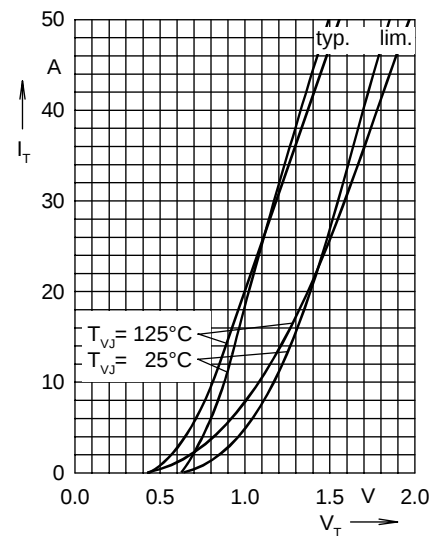


Fig. 3 On-state characteristics

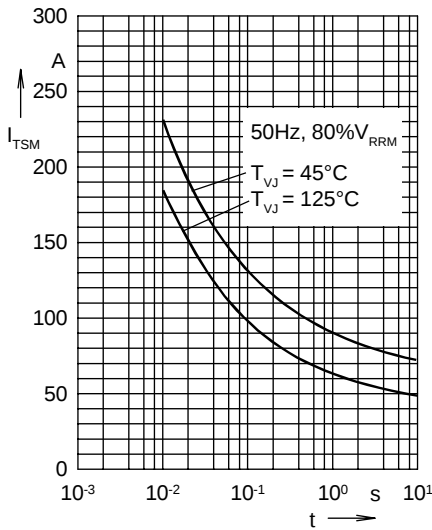


Fig. 4 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : duration

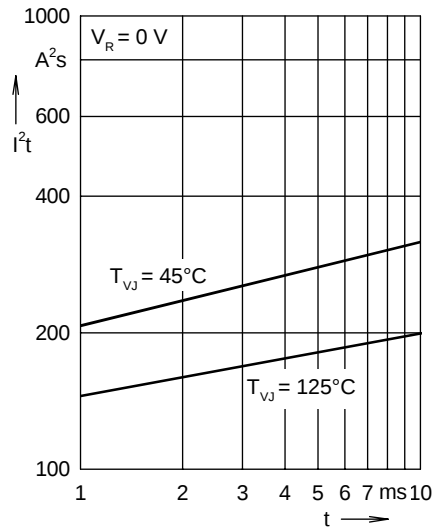


Fig. 5  $I^2t$  versus time (1-10 ms)

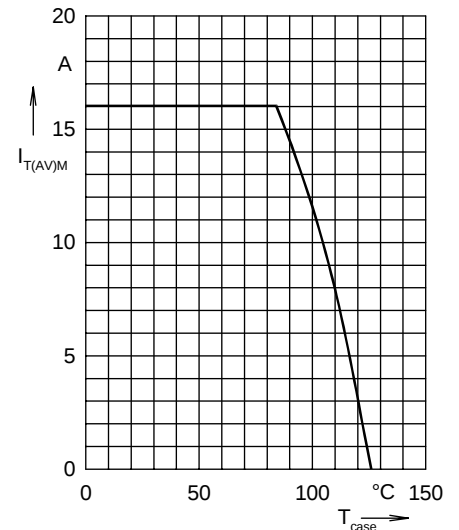


Fig. 6 Maximum forward current at case temperature 180° sine

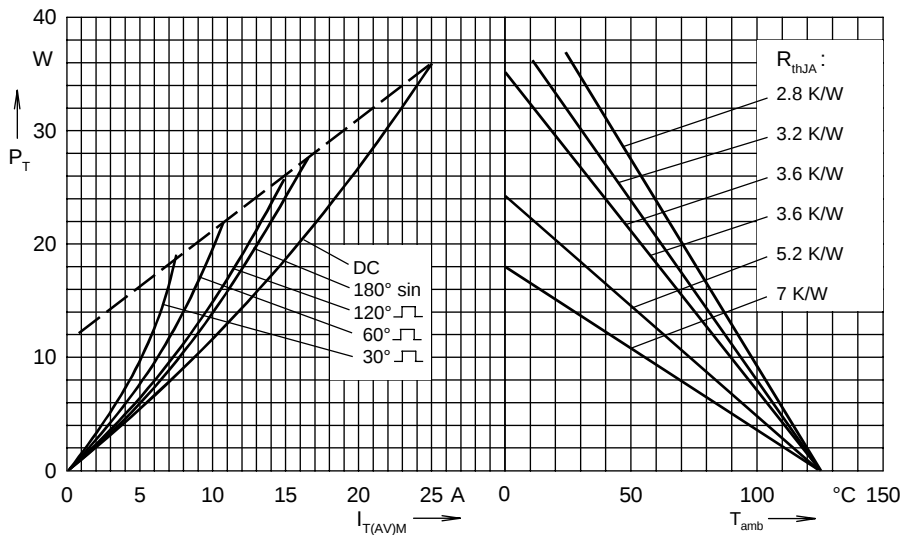


Fig. 7 Power dissipation versus on-state current and ambient temperature

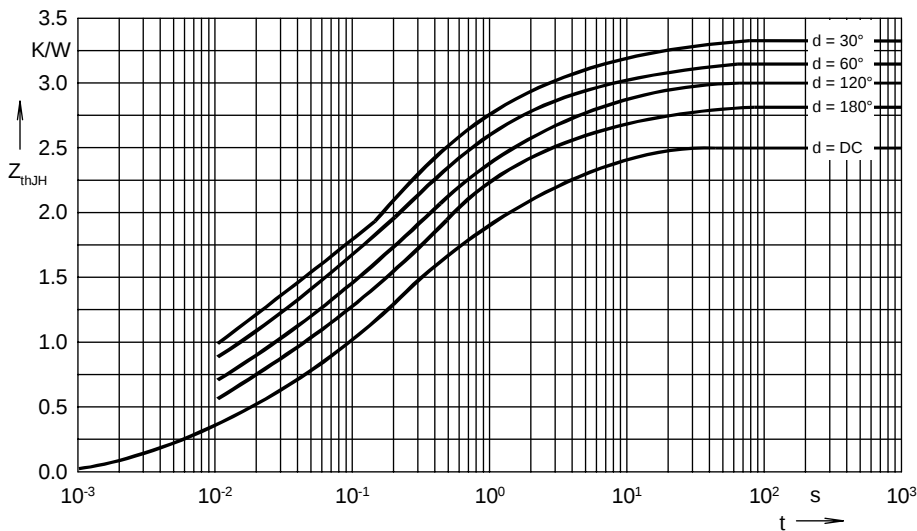


Fig. 8 Transient thermal impedance junction to heatsink

$R_{thJH}$  for various conduction angles  $d$ :

| $d$  | $R_{thJH}$ (K/W) |
|------|------------------|
| DC   | 2.5              |
| 180° | 2.79             |
| 120° | 2.95             |
| 60°  | 3.17             |
| 30°  | 3.32             |

Constants for  $Z_{thJH}$  calculation:

| $i$ | $R_{thi}$ (K/W) | $t_i$ (s) |
|-----|-----------------|-----------|
| 1   | 0.252           | 0.005     |
| 2   | 0.333           | 0.0225    |
| 3   | 0.5             | 0.145     |
| 4   | 0.833           | 0.43      |
| 5   | 0.416           | 2.75      |
| 6   | 0.166           | 23        |